

New Product

Vishay General Semiconductor

Glass Passivated Junction Rectifier

Major Ratings and Characteristics

I _{F(AV)}	1.0 A
V _{RRM}	50 V to 1000 V
I _{FSM}	30 A
I _R	5.0 μΑ
V _F	1.1 V
T _j max.	150 °C



Features

- · Glass passivated chip junction
- · Low forward voltage drop
- Low leakage current, typical I_R less than 0.1 μA
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Solder Dip 260 °C, 40 seconds

Mechanical Data

Case: DO-204AL, molded epoxy over passivated chip

Epoxy meets UL-94V-0 Flammability rating Terminals: Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and JESD22-B102D

Polarity: Color band denotes cathode end

Typical Applications

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application

Maximum Ratings

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

Parameter	Symbol	GPP10A	GPP10B	GPP10D	GPP10G	GPP10J	GPP10K	GPP10M	Unit
* Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
* Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
* Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
* Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_{A}=75~^{\circ}\text{C}$	I _{F(AV)}	1.0							Α
* Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30							А
* Maximum full load reverse current, full cycle average 0.375" (9.5 mm) lead length $T_A=75~^{\circ}\text{C}$	I _{R(AV)}	30							μА
* Operating junction and storage temperature range	T_J , T_{STG}	- 55 to + 150							°C

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GPP10A thru GPP10M

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Electrical Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Test condition	Symbol	GPP10A	GPP10B	GPP10D	GPP10G	GPP10J	GPP10K	GPP10M	Unit
Maximum instantaneous forward voltage	at 1.0 A	V _F				1.1				V
* Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C T _A = 100 °C	I _R	5.0 50						μА	
Maximum junction capacitance	at 4.0 V, 1 MHz	СЈ				6				pF

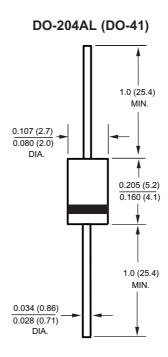
Thermal Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Symbol	GPP10A	GPP10B	GPP10D	GPP10G	GPP10J	GPP10K	GPP10M	Unit
Typical thermal resistance ⁽¹⁾	$R_{\theta JA}$	50						°C/W	
	$R_{\theta JL}$	25							

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

Package outline dimensions in inches (millimeters)



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^{*} JEDEC registered values

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